SCBS687H - MAY 1997 - REVISED SEPTEMBER 2003

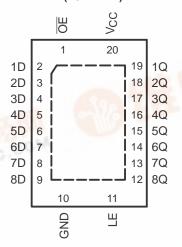
- Support Mixed-Mode Signal Operation (5-V Input and Output Voltages With 3.3-V V_{CC})
- **Support Unregulated Battery Operation** Down to 2.7 V
- Typical V_{OLP} (Output Ground Bounce) <0.8 V at $V_{CC} = 3.3 \text{ V}, T_A = 25^{\circ}\text{C}$
- Ioff and Power-Up 3-State Support Hot Insertion

- Bus Hold on Data Inputs Eliminates the Need for External Pullup/Pulldown Resistors
- Latch-Up Performance Exceeds 500 mA Per JESD 17
- **ESD Protection Exceeds JESD 22**
 - 2000-V Human-Body Model (A114-A)
 - 200-V Machine Model (A115-A)

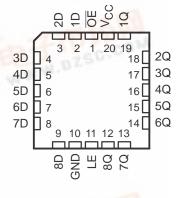
SN54LVTH573...J OR W PACKAGE SN74LVTH573 . . . DB, DW, NS, **OR PW PACKAGE** (TOP VIEW)



SN74LVTH573 . . . RGY PACKAGE (TOP VIEW)



SN54LVTH573 . . . FK PACKAGE (TOP VIEW)



description/ordering information

ORDERING INFORMATION

TA	PACKAGE	t and	ORDERABLE PART NUMBER	TOP-SIDE MARKING
- N. C. Same 1	QFN – RGY	Tape and reel	SN74LVTH573RGYR	LXH573
CHILE	COIC DW	Tube	SN74LVTH573DW	LVTH573
FR In	SOIC - DW	Tape and reel	SN74LVTH573DWR	LVTH573
	SOP - NS	Tape and reel	SN74LVTH573NSR	LVTH573
-40°C to 85°C	SSOP - DB	Tape and reel	SN74LVTH573DBR	LXH573
	TOOOD DW	Tube	SN74LVTH573PW	1 VI 1570 7 5 G . 15 C
	TSSOP – PW	Tape and reel	SN74LVTH573PWR	LXH573
	VFBGA – GQN	- 1.886	SN74LVTH573GQNR	17/1520
	VFBGA – ZQN (Pb-free)	Tape and reel	SN74LVTH573ZQNR	LXH573
160	CDIP – J	Tube	SNJ54LVTH573J	SNJ54LVTH573J
–55°C to 125°C	CFP – W	Tube	SNJ54LVTH573W	SNJ54LVTH573W
	LCCC - FK	Tube	SNJ54LVTH573FK	SNJ54LVTH573FK

Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of



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description/ordering information (continued)

These octal latches are designed specifically for low-voltage (3.3-V) V_{CC} operation, but with the capability to provide a TTL interface to a 5-V system environment.

The eight latches of the 'LVTH573 devices are transparent D-type latches. While the latch-enable (LE) input is high, the Q outputs follow the data (D) inputs. When LE is taken low, the Q outputs are latched at the logic levels set up at the D inputs.

A buffered output-enable (OE) input can be used to place the eight outputs in either a normal logic state (high or low logic levels) or a high-impedance state. In the high-impedance state, the outputs neither load nor drive the bus lines significantly. The high-impedance state and increased drive provide the capability to drive bus lines without need for interface or pullup components.

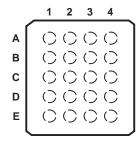
 $\overline{\text{OE}}$ does not affect the internal operations of the latches. Old data can be retained or new data can be entered while the outputs are in the high-impedance state.

To ensure the high-impedance state during power up or power down, \overline{OE} should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

Active bus-hold circuitry is provided to hold unused or floating data inputs at a valid logic level. Use of pullup or pulldown resistors with the bus-hold circuitry is not recommended.

These devices are fully specified for hot-insertion applications using I_{off} and power-up 3-state. The I_{off} circuitry disables the outputs, preventing damaging current backflow through the devices when they are powered down. The power-up 3-state circuitry places the outputs in the high-impedance state during power up and power down, which prevents driver conflict.

SN74LVTH573 . . . GQN OR ZQN PACKAGE (TOP VIEW)



terminal assignments

	1	2	3	4
Α	1D	OE	VCC	1Q
В	3D	3Q	2D	2Q
С	5D	4D	5Q	4Q
D	7D	7Q	6D	6Q
Е	GND	8D	LE	8Q

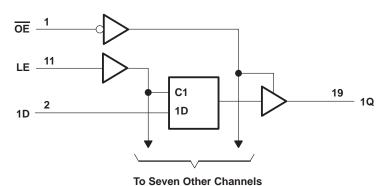
FUNCTION TABLE (each latch)

	OUTPUT			
OE	LE	D	Q	
L	Н	Н	Н	
L	Н	L	L	
L	L	Χ	Q_0	
Н	Χ	Χ	Z	



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logic diagram (positive logic)



Pin numbers shown are for the DB, DW, FK, J, NS, PW, RGY, and W packages.

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)

Supply voltage range, V _{CC} 0	0.5 V to 4.6 V
Input voltage range, V _I (see Note 1)	
Voltage range applied to any output in the high-impedance	
or power-off state, V _O (see Note 1)	-0.5 V to 7 V
Voltage range applied to any output in the high state, V _O (see Note 1)0.5 V to	$V_{CC} + 0.5 V$
Current into any output in the low state, IO: SN54LVTH573	96 mA
SN74LVTH573	128 mA
Current into any output in the high state, I _O (see Note 2): SN54LVTH573	48 mA
SN74LVTH573	64 mA
Input clamp current, $I_{ K }(V_{ I } < 0)$	–50 mA
Output clamp current, I _{OK} (V _O < 0)	–50 mA
Package thermal impedance, θ _{JA} (see Note 3): DB package	70°C/W
(see Note 3): DW package	58°C/W
(see Note 3): GQN/ZQN package	78°C/W
(see Note 3): NS package	60°C/W
(see Note 3): PW package	83°C/W
(see Note 4): RGY package	37°C/W
Storage temperature range, T _{stq} –65	5°C to 150°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. The input and output negative-voltage ratings may be exceeded if the input and output clamp-current ratings are observed.

- 2. This current flows only when the output is in the high state and $V_O > V_{CC}$.
- 3. The package thermal impedance is calculated in accordance with JESD 51-7.
- 4. The package thermal impedance is calculated in accordance with JESD 51-5.



SN54LVTH573, SN74LVTH573 3.3-V ABT OCTAL TRANSPARENT D-TYPE LATCHES WITH 3-STATE OUTPUTS SCBS687H - MAY 1997 - REVISED SEPTEMBER 2003

recommended operating conditions (see Note 5)

			SN54LV	TH573	SN74LV	TH573	
			MIN	MAX	MIN	MAX	UNIT
VCC	Supply voltage		2.7	3.6	2.7	3.6	V
VIH	High-level input voltage				2		V
V _{IL}	Low-level input voltage					0.8	V
VI	Input voltage					5.5	V
ЮН	High-level output current			-24		-32	mA
lOL	Low-level output current			48		64	mA
Δt/Δν	Input transition rise or fall rate	Outputs enabled		10		10	ns/V
Δt/ΔV _{CC}	Power-up ramp rate		200		200		μs/V
TA	Operating free-air temperature	Operating free-air temperature				85	°C

NOTE 5: All unused control inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

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electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

DADAMETER		TEGT COMPITIONS		SN	SN54LVTH573			SN74LVTH573			
PAI	PARAMETER TEST CONDITIONS		MIN	TYP [†]	MAX	MIN	TYP [†]	MAX	UNIT		
VIK		$V_{CC} = 2.7 \text{ V},$	I _I = -18 mA			-1.2			-1.2	V	
		$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V},$	$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}, \qquad I_{OH} = -100 \mu\text{A}$.2		VCC-0	.2			
V/		$V_{CC} = 2.7 \text{ V},$	$I_{OH} = -8 \text{ mA}$	2.4			2.4			V	
VOH		\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\	$I_{OH} = -24 \text{ mA}$	2						V	
		VCC = 3 V	$I_{OH} = -32 \text{ mA}$				2				
		V _{CC} = 2.7 V	I _{OL} = 100 μA			0.2			0.2		
		vCC = 2.7 v	I _{OL} = 24 mA			0.5			0.5		
\/-·			I _{OL} = 16 mA			0.4			0.4	V	
V_{OL}		V _{CC} = 3 V	$I_{OL} = 32 \text{ mA}$			0.5			0.5	V	
		ACC = 2 A	I _{OL} = 48 mA			0.55					
			$I_{OL} = 64 \text{ mA}$						0.55		
	Control in next	$V_{CC} = 0 \text{ or } 3.6 \text{ V},$	V _I = 5.5 V			10			10		
1.	Control inputs	$V_{CC} = 3.6 \text{ V},$	$V_I = V_{CC}$ or GND			±1			±1		
I _I	Data innuta	V _{CC} = 3.6 V	VI = VCC			1			1	μΑ	
	Data inputs		V _I = 0			-5			-5		
l _{off}		$V_{CC} = 0$,	V_I or $V_O = 0$ to 4.5 V						±100	μΑ	
		V 2 V	V _I = 0.8 V	75			75				
l _l (hold)	Data inputs	VCC = 3 V	V _I = 2 V	-75			-75			μΑ	
		$V_{CC} = 3.6 V^{\ddagger}$,	$V_{I} = 0 \text{ to } 3.6 \text{ V}$						±500		
lozh		$V_{CC} = 3.6 \text{ V},$	V _O = 3 V			5			5	μΑ	
lozL		$V_{CC} = 3.6 \text{ V},$	$V_0 = 0.5 \text{ V}$			-5			-5	μΑ	
IOZPU		$\frac{V_{CC}}{OE} = 0$ to 1.5 V, $V_{O} = \frac{V_{CC}}{OE} = 0$	0.5 V to 3 V,			±100*			±100	μΑ	
IOZPD		$\frac{V_{CC}}{OE}$ = 1.5 V to 0, V_{O} = $\frac{V_{CC}}{OE}$ = don't care	0.5 V to 3 V,			±100*			±100	μΑ	
ICC		V _{CC} = 3.6 V,	Outputs high			0.19			0.19		
		$I_{O}=0$,	Outputs low			5			5	mA	
		$V_I = V_{CC}$ or GND	Outputs disabled			0.19			0.19		
ΔlCC§		$V_{CC} = 3 \text{ V to } 3.6 \text{ V, On}$ Other inputs at V_{CC} or				0.2			0.2	mA	
Ci		V _I = 3 V or 0			3			3		pF	
Co		V _O = 3 V or 0			7			7		pF	

 $^{^{\}star}\!\text{On}$ products compliant to MIL-PRF-38535, this parameter is not production tested.



[†] All typical values are at V_{CC} = 3.3 V, T_A = 25°C.

[‡] This is the bus-hold maximum dynamic current. It is the minimum overdrive current required to switch the input from one state to another.

[§] This is the increase in supply current for each input that is at the specified TTL voltage level, rather than V_{CC} or GND.

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timing requirements over recommended operating free-air temperature range (unless otherwise noted) (see Figure 1)

			SN54LVTH573				SN74LVTH573			
		V _{CC} =	3.3 V 3 V	VCC =	2.7 V	V _{CC} =	3.3 V 3 V	VCC =	2.7 V	UNIT
		MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
t _W	Pulse duration, LE high	3		3		3		3		ns
t _{su}	Setup time, data before LE↓	0.7		0.6		0.7		0.6		ns
th	Hold time, data after LE↓	1.5		1.7		1.5		1.7		ns

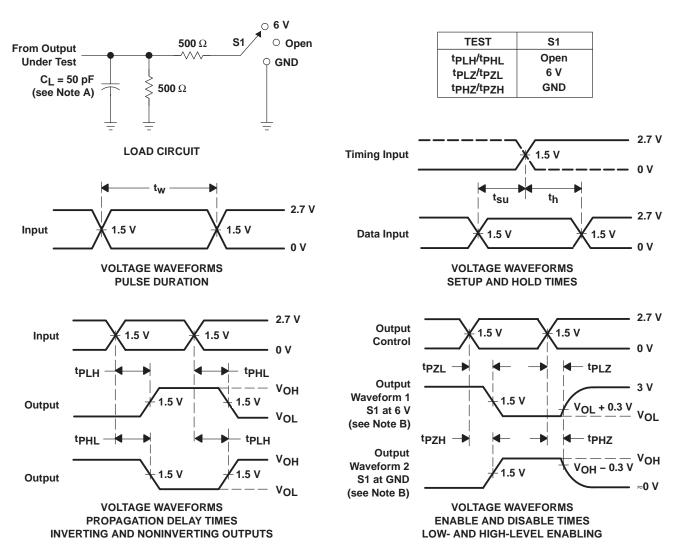
switching characteristics over recommended free-air temperature, $C_L = 50$ pF (unless otherwise noted) (see Figure 1)

			SN54LVTH573				SN74LVTH573					
PARAMETER	FROM (INPUT)		V _{CC} = 3.3 V ± 0.3 V		V _{CC} = 2.7 V		V _{CC} = 3.3 V ± 0.3 V		٧	V _{CC} = 2.7 V		UNIT
			MIN	MAX	MIN	MAX	MIN	TYP†	MAX	MIN	MAX	
tPLH	D	0	1.4	4.1		4.7	1.5	2.6	3.9		4.5	20
t _{PHL}	D	Q	1.4	4.5		4.8	1.5	2.9	3.9		4.5	ns
tPLH	LE	_	1	4.4		5.4	1.9	2.9	4.2		4.9	
t _{PHL}	LE	Q	1.4	4.4		5.1	1.9	2.9	4.2		4.9	ns
^t PZH	ŌĒ	0	1.4	5.2		6.2	1.5	3.2	5.1		5.9	
t _{PZL}		Q	1.4	5.2		6.2	1.5	3.9	5.1		5.9	ns
^t PHZ	ŌĒ	0	1.2	5.4		5.7	2	3.5	4.9		5.5	20
tPLZ	OE.	Q	1	5.2		5.2	2	3.2	4.6		4.9	ns

[†] All typical values are at $V_{CC} = 3.3 \text{ V}$, $T_A = 25^{\circ}\text{C}$.

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PARAMETER MEASUREMENT INFORMATION



NOTES: A. C_I includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, Z_{O} = 50 Ω , $t_{f} \leq$ 2.5 ns. $t_{f} \leq$ 2.5 ns.
- D. The outputs are measured one at a time with one transition per measurement.
- E. All parameters and waveforms are not applicable to all devices.

Figure 1. Load Circuit and Voltage Waveforms



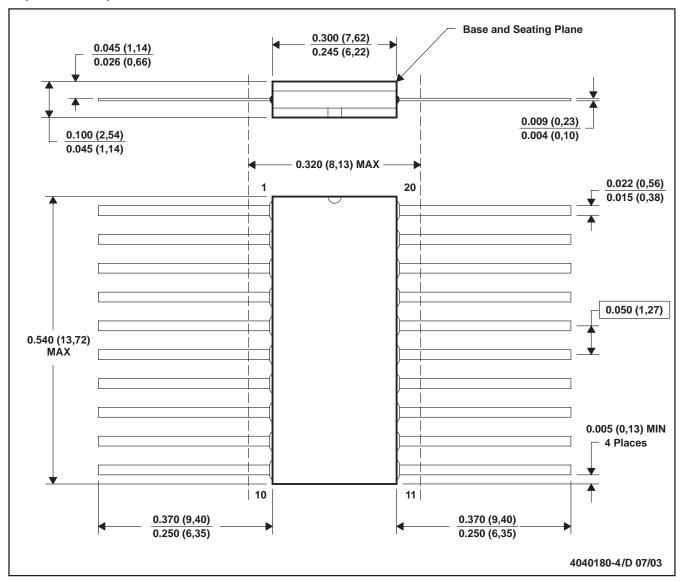


NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package is hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
- E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

W (R-GDFP-F20)

CERAMIC DUAL FLATPACK



NOTES: A. All linear dimensions are in inches (millimeters).

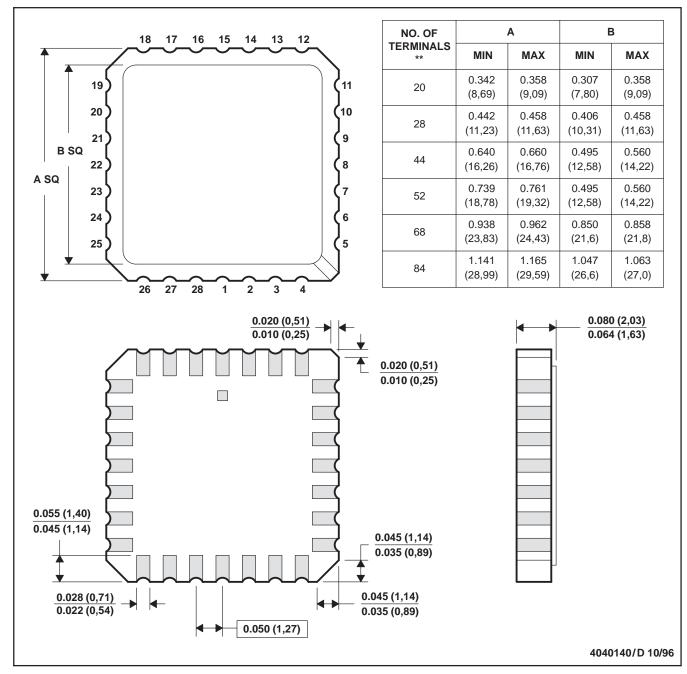
- B. This drawing is subject to change without notice.
- C. This package can be hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only.
- E. Falls within Mil-Std 1835 GDFP2-F20



FK (S-CQCC-N**)

28 TERMINAL SHOWN

LEADLESS CERAMIC CHIP CARRIER

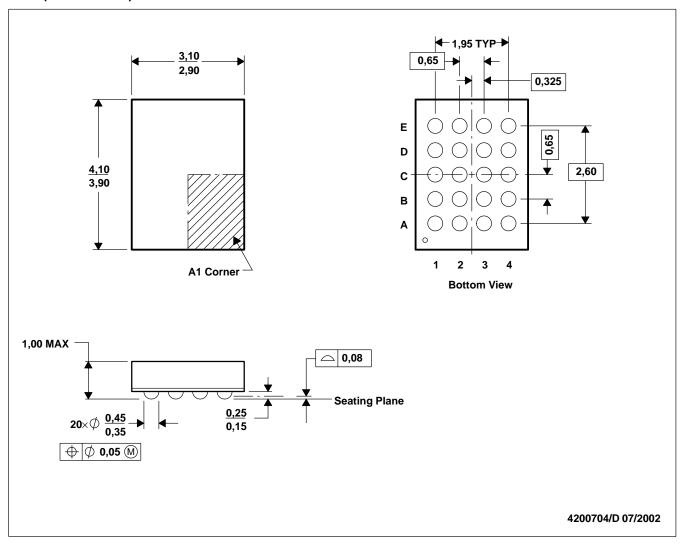


- NOTES: A. All linear dimensions are in inches (millimeters).
 - B. This drawing is subject to change without notice.
 - C. This package can be hermetically sealed with a metal lid.
 - D. The terminals are gold plated.
 - E. Falls within JEDEC MS-004



GQN (R-PBGA-N20)

PLASTIC BALL GRID ARRAY



NOTES: A. All linear dimensions are in millimeters.

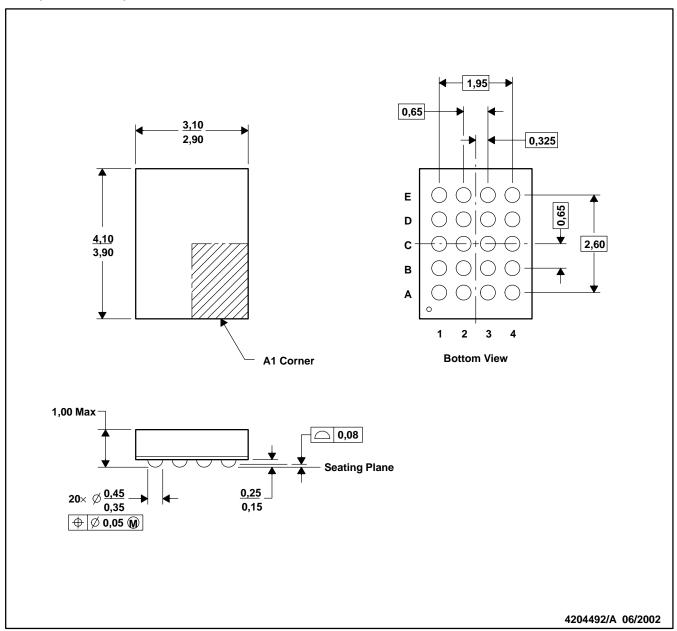
- B. This drawing is subject to change without notice.
- C. MicroStar Junior™ configuration
- D. Falls within JEDEC MO-225 variation BC.
- E. This package is tin-lead (SnPb). Refer to the 20 ZQN package (drawing 4204492) for lead-free.

MicroStar Junior is a trademark of Texas Instruments.



ZQN (R-PBGA-N20)

PLASTIC BALL GRID ARRAY

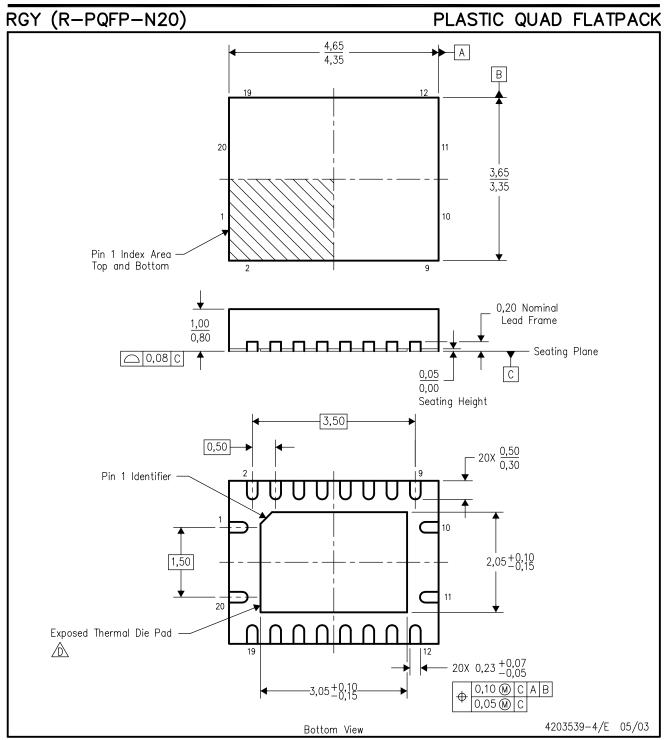


NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. MicroStar Junior™ configuration.
- D. Fall within JEDEC MO-225 variation BC.
- E. This package is lead-free. Refer to the 20 GQN package (drawing 4200704) for tin-lead)SnPb).

MicroStar Junior is a trademark of Texas Instruments.





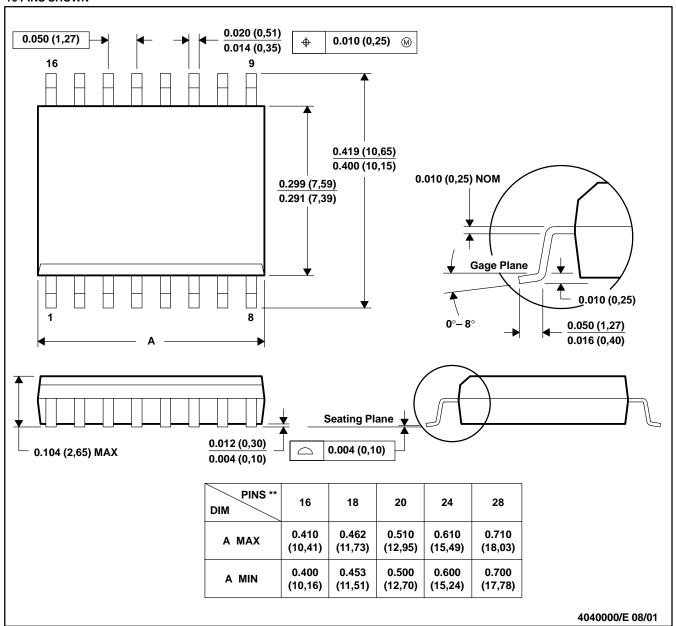
- NOTES: A. All linear dimensions are in millimeters.
 - B. This drawing is subject to change without notice.
 - C. QFN (Quad Flatpack No-Lead) package configuration.
 - The package thermal performance may be enhanced by bonding the thermal die pad to an external thermal plane. This pad is electrically and thermally connected to the backside of the die and possibly selected ground leads.
 - E. Package complies to JEDEC MO-241 variation BC.



DW (R-PDSO-G**)

PLASTIC SMALL-OUTLINE PACKAGE

16 PINS SHOWN



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
- D. Falls within JEDEC MS-013



MECHANICAL DATA

NS (R-PDSO-G**)

14-PINS SHOWN

PLASTIC SMALL-OUTLINE PACKAGE



NOTES:

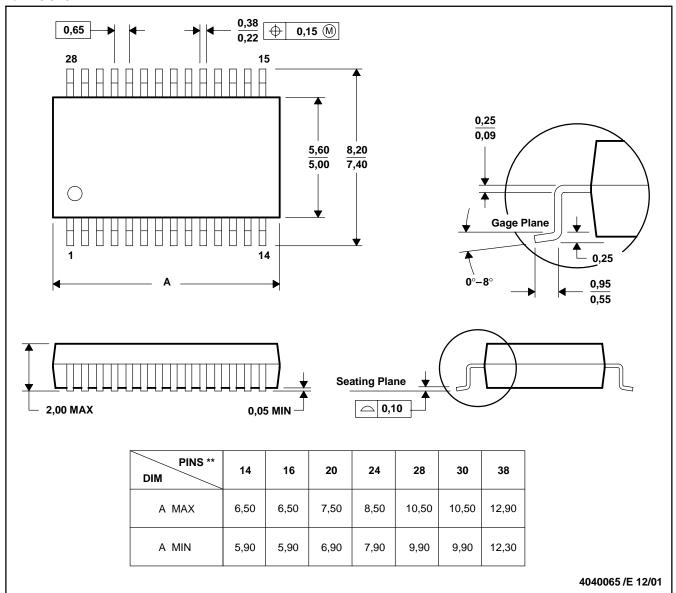
- . All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



DB (R-PDSO-G**)

PLASTIC SMALL-OUTLINE

28 PINS SHOWN



NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.
- D. Falls within JEDEC MO-150



PW (R-PDSO-G**)

14 PINS SHOWN

PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.

D. Falls within JEDEC MO-153

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